DATASHEET

### **Description**

The 9ZX21901D is a second generation DB1900Z differential buffer for Intel Purley and newer platforms. The part is backwards compatible to the 9ZX21901C while offering much improved phase jitter performance. A fixed external feedback maintains low drift for critical QPI/UPI applications. In bypass mode, the 9ZX21901D can provide outputs up to 400MHz.

## PCIe Clocking Architectures Supported

- Common Clocked (CC)
- Separate Reference No Spread (SRNS)
- Separate Reference Independent Spread (SRIS)

## Typical Applications

· Servers, Storage, Networking

#### **Output Features**

• 19 HCSL output pairs

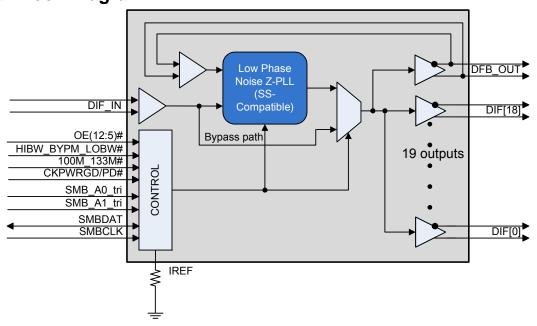
#### **Key Specifications**

- Cycle-to-cycle jitter: < 50ps
- Output-to-output skew: < 50ps
- Input-to-output delay: Fixed at 0 ps
- Input-to-output delay variation: < 50ps</li>
- Phase jitter: PCIe Gen4 < 0.5ps rms
- Phase jitter: UPI 9.6GB/s < 0.1ps rms

#### **Features**

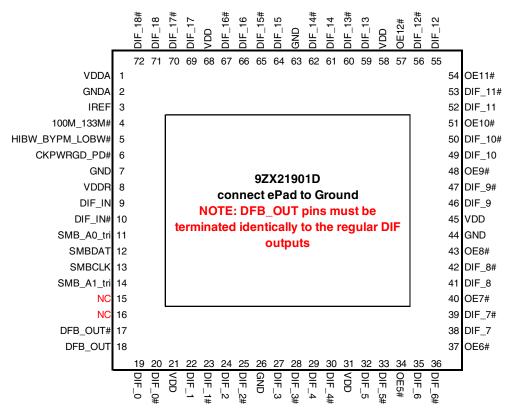
- Fixed feedback path; Ops input-to-output delay
- 9 Selectable SMBus addresses; multiple devices can share same SMBus segment
- 8 dedicated OE# pins; hardware control of outputs
- PLL or bypass mode; PLL can dejitter incoming clock
- Selectable PLL BW; minimizes jitter peaking in downstream PLL's
- Hardware or software control of PLL operating mode; change mode with software mode does not need power cycle
- Spread spectrum compatible; tracks spreading input clock for EMI reduction
- SMBus Interface; unused outputs can be disabled
- 100MHz and 133.33MHz PLL mode; legacy QPI support
- 72-QFN 10 x 10 mm package; small board footprint

# **Functional Block Diagram**





## **Pin Configuration**



72-pin VFQFPN (10mm x10 mm, 0.5mm pad pitch)

Functionality at Power Up (PLL Mode)

100M_133M#	DIF_IN (MHz)	DIF_x (MHz)		
1	100.00	DIF_IN		
0	133.33	DIF_IN		

**PLL Operating Mode Readback Table** 

· LE operating mode nedablest rable								
HiBW_BypM_LoBW#	Byte0, bit 7	Byte 0, bit 6						
Low (Low BW)	0	0						
Mid (Bypass)	0	1						
High (High BW)	1	1						

**PLL Operating Mode** 

HiBW_BypM_LoBW#	MODE
Low	PLL Lo BW
Mid	Bypass
High	PLL Hi BW

NOTE: PLL is OFF in Bypass Mode

**Tri-level Input Thresholds** 

Level	Voltage
Low	<0.8V
Mid	1.2 <vin<1.8v< td=""></vin<1.8v<>
High	Vin > 2.2V

#### **Power Connections**

Pin Nu	ımber	
VDD GND		Description
1	2	Analog PLL
8	7	Analog Input
21, 31, 45, 58, 68	26, 44, 63	DIF clocks

9ZX21901 SMBus Addressing

Pi	n	SMBus Address
SMB_A1_tri	SMB_A0_tri	(Rd/Wrt bit = 0)
0	0	D8
0	М	DA
0	1	DE
М	0	C2
M	М	C4
М	1	C6
1	0	CA
1	M	CC
1	1	CE



# **Pin Descriptions**

PIN#	PIN NAME	PIN TYPE	DESCRIPTION
1	VDDA	PWR	Power supply for PLL core.
2	GNDA	GND	Ground pin for the PLL core.
			This pin establishes the reference for the differential current-mode output pairs.
3	IREF	OUT	It requires a fixed precision resistor to ground. 475ohm is the standard value
3	IREF	001	for 100ohm differential impedance. Other impedances require different values.
			See data sheet.
4	100M 122M#	IN	Input to select operating frequency
4	100M_133M#	IIN	1 = 100MHz, 0 = 133.33MHz
5	HIBW_BYPM_LOBW#	IN	Tri-level input to select High BW, Bypass or Low BW mode.
3	THOW_DIT W_LODW#	111	See PLL Operating Mode Table for Details.
			3.3V input notifies device to sample latched inputs and start up on first high
6	CKPWRGD_PD#	IN	assertion, or exit Power Down Mode on subsequent assertions. Low enters
			Power Down Mode.
7	GND	GND	Ground pin.
8	VDDR	PWR	Power supply for differential input clock (receiver). This VDD should be treated
0	VDDIT	1 7711	as an analog power rail and filtered appropriately. Nominally 3.3V.
9	DIF_IN	IN	HCSL true input.
10	DIF_IN#	IN	HCSL complementary input.
11	SMB_A0_tri	IN	SMBus address pin. This is a tri-level input that works in conjunction with other
		\	SMBus address pins to decode 3^n SMBus addresses, where n is the number
12	SMBDAT	I/O	Data pin of SMBUS circuitry
13	SMBCLK	IN	Clock pin of SMBUS circuitry
14	SMB_A1_tri	IN	SMBus address pin. This is a tri-level input that works in conjunction with other
			SMBus address pins to decode 3^n SMBus addresses, where n is the number
15	NC	N/A	No connection.
16	NC	N/A	No connection.
47	DED OUT#		Complementary half of differential feedback output, provides feedback signal
17	DFB_OUT#	OUT	to the PLL for synchronization with input clock to eliminate phase error.
		+ +	True half of differential feedback output, provides feedback signal to the PLL
18	DFB_OUT	OUT	for synchronization with the input clock to eliminate phase error.
19	DIF_0	OUT	HCSL true clock output.
20	DIF_0#	OUT	HCSL complementary clock output.
21	VDD	PWR	Power supply, nominally 3.3V.
22	DIF_1	OUT	HCSL true clock output.
23	DIF 1#	OUT	HCSL complementary clock output.
24	DIF_2	OUT	HCSL true clock output.
25	DIF_2#	OUT	HCSL complementary clock output.
26	GND	GND	Ground pin.
27	DIF_3	OUT	HCSL true clock output.
28	DIF_3#	OUT	HCSL complementary clock output.
29	DIF_4	OUT	HCSL true clock output.
30	DIF_4#	OUT	HCSL complementary clock output.
31	VDD	PWR	Power supply, nominally 3.3V.
32	DIF_5	OUT	HCSL true clock output.
33	 DIF_5#	OUT	HCSL complementary clock output.
			Active low input for enabling output 5.
34	OE5#	IN	1 = disable outputs, 0 = enable outputs.
35	DIF_6	OUT	HCSL true clock output.
36	 DIF_6#	OUT	HCSL complementary clock output.



# Pin Descriptions (cont.)

PIN#	PIN NAME	PIN TYPE	DESCRIPTION
37	OE6#	IN	Active low input for enabling DIF pair 6.
37	OE6#	IIN	1 =disable outputs, 0 = enable outputs
38	DIF_7	OUT	HCSL true clock output
39	DIF_7#	OUT	HCSL Complementary clock output
40	OE7#	IN	Active low input for enabling DIF pair 7.
40	OE7#	IIN	1 =disable outputs, 0 = enable outputs
41	DIF_8	OUT	HCSL true clock output
42	DIF_8#	OUT	HCSL Complementary clock output
43	OE8#	IN	Active low input for enabling DIF pair 8.
+0			1 =disable outputs, 0 = enable outputs
44	GND	GND	Ground pin.
45	VDD	PWR	Power supply, nominal 3.3V
46	DIF_9	OUT	HCSL true clock output
47	DIF_9#	OUT	HCSL Complementary clock output
48	OE9#	IN	Active low input for enabling DIF pair 9.
			1 =disable outputs, 0 = enable outputs
49	DIF_10	OUT	HCSL true clock output
50	DIF_10#	OUT	HCSL Complementary clock output
51	OE10#	IN	Active low input for enabling DIF pair 10.
			1 =disable outputs, 0 = enable outputs
52	DIF_11	OUT	HCSL true clock output
53	DIF_11#	OUT	HCSL Complementary clock output
54	OE11#	IN	Active low input for enabling DIF pair 11.
			1 =disable outputs, 0 = enable outputs
55	DIF_12	OUT	HCSL true clock output
56	DIF_12#	OUT	HCSL Complementary clock output
57	OE12#	IN	Active low input for enabling DIF pair 12.
	VDD	DWD	1 =disable outputs, 0 = enable outputs
58	VDD	PWR	Power supply, nominal 3.3V
59	DIF_13	OUT	HCSL true clock output
60 61	DIF_13# DIF_14	OUT	HCSL Complementary clock output  HCSL true clock output
62	DIF_14 DIF_14#	OUT	HCSL Complementary clock output
63	GND	GND	Ground pin.
64	DIF_15	OUT	HCSL true clock output
65	DIF_15#	OUT	HCSL Complementary clock output
66	DIF_16	OUT	HCSL true clock output
67	DIF_16#	OUT	HCSL Complementary clock output
68	VDD	PWR	Power supply, nominal 3.3V
69	DIF_17	OUT	HCSL true clock output
70	DIF_17#	OUT	HCSL Complementary clock output
71	DIF_18	OUT	HCSL true clock output
72	DIF_18#	OUT	HCSL Complementary clock output



## **Electrical Characteristics – Absolute Maximum Ratings**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx				3.9	V	1,2
Input Low Voltage	$V_{IL}$		GND-0.5			V	1
Input High Voltage	$V_{IH}$	Except for SMBus interface			V <sub>DD</sub> +0.5	V	1,3
Input High Voltage	V <sub>IHSMB</sub>	SMBus clock and data pins			3.9	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

#### **Electrical Characteristics – DIF\_IN Clock Input Parameters**

Over specified temperature and voltage ranges unless otherwise indicated. See Test Loads for loading conditions.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage	V <sub>CROSS</sub>	Crossover voltage	150		900	mV	1
Input Swing - DIF_IN	V <sub>SWING</sub>	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.35		8	V/ns	1,2
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{DD}$ , $V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d <sub>tin</sub>	Measurement from differential waveform	45		55	%	1
Input Jitter - Cycle to Cycle	$J_{DIFIn}$	Differential measurement	0		125	ps	1

<sup>&</sup>lt;sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

#### **Electrical Characteristics – SMBus**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
SMBus Input Low Voltage	V <sub>ILSMB</sub>				0.8	V	
SMBus Input High Voltage	$V_{IHSMB}$		2.1		$V_{\text{DDSMB}}$	V	
SMBus Output Low Voltage	$V_{OLSMB}$	@ I <sub>PULLUP</sub>			0.4	V	
SMBus Sink Current	I <sub>PULLUP</sub>	@ V <sub>OL</sub>	4			mA	
Nominal Bus Voltage	$V_{\rm DDSMB}$		2.7		3.6	V	1
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			400	kHz	5

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> Operation under these conditions is neither implied nor guaranteed.

<sup>&</sup>lt;sup>3</sup> Not to exceed 3.9V.

<sup>&</sup>lt;sup>2</sup>Slew rate measured through +/-75mV window centered around differential zero.

<sup>&</sup>lt;sup>2</sup>Control input must be monotonic from 20% to 80% of input swing.

<sup>&</sup>lt;sup>3</sup>Time from deassertion until outputs are >200 mV

<sup>&</sup>lt;sup>4</sup>DIF\_IN input

<sup>&</sup>lt;sup>5</sup>The differential input clock must be running for the SMBus to be active



## **Electrical Characteristics – Current Consumption**

Over specified temperature and voltage ranges unless otherwise indicated. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I <sub>DDA</sub>	VDDA, PLL Mode@100MHz		42	45	mA	1
Operating Supply Current	I <sub>DD</sub>	All other VDD pins		466	490	mA	
Powerdown Current	I <sub>DDPD</sub>	All DIF pairs Hi-Z		4	5	mA	

<sup>1.</sup> Includes VDDR if applicable

## **Electrical Characteristics – Input/Supply/Common Parameters**

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Supply voltage for core and analog	3.135	3.3	3.465	V	
Ambient Operating Temperature	T <sub>AMB</sub>	Commercial range (T <sub>COM</sub> )	0		70	°C	
Input High Voltage	V <sub>IH</sub>	Single-ended inputs, except SMBus, tri-level inputs	2		V <sub>DD</sub> + 0.3	٧	
Input Low Voltage	V <sub>IL</sub>	Single-ended inputs, except SMBus, tri-level inputs	GND - 0.3		0.8	٧	
Input High Voltage	$V_{IH}$	Tri-Level Inputs	2.2		$V_{DD} + 0.3$	V	
Input Mid Voltage	$V_{IL}$	Tri-Level Inputs	1.2	VDD/2	1.8	V	
Input Low Voltage	V <sub>IL</sub>	Tri-Level Inputs	GND - 0.3		0.8	V	
	I <sub>IN</sub>	Single-ended inputs, $V_{IN} = GND$ , $V_{IN} = VDD$	-5		5	μΑ	
Input Current	I <sub>INP</sub>	$\label{eq:VIN} Single-ended inputs \\ V_{IN} = 0 \text{ V}; \text{ Inputs with internal pull-up resistors} \\ V_{IN} = \text{VDD}; \text{ Inputs with internal pull-down resistors}$	-200		200	μΑ	
	$F_{ibyp}$	V <sub>DD</sub> = 3.3 V, Bypass mode	33		400	MHz	
Input Frequency	$F_{ipII}$	$V_{DD} = 3.3 \text{ V}, 100\text{MHz PLL mode}$	98.5	100.00	102	MHz	
	F <sub>ipII</sub>	$V_{DD} = 3.3 V$ , 133.33MHz PLL mode	125	130.50	135	MHz	
Pin Inductance	$L_{pin}$				7	nΗ	1
	C <sub>IN</sub>	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C <sub>INDIF_IN</sub>	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
	C <sub>OUT</sub>	Output pin capacitance			6	pF	1
Clk Stabilization	T <sub>STAB</sub>	From V <sub>DD</sub> Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		1.4	1.8	ms	1,2
Input SS Modulation Frequency PCIe	f <sub>MODINPCle</sub>	Allowable Frequency for PCIe Applications (Triangular Modulation)	30		33	kHz	
OE# Latency	t <sub>LATOE#</sub>	DIF start after OE# assertion DIF stop after OE# deassertion	4	6	10	clocks	1,2,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion		85	300	μs	1,3
Tfall	t <sub>F</sub>	Fall time of control inputs			5	ns	2
Trise	$t_R$	Rise time of control inputs			5	ns	2

<sup>&</sup>lt;sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

 $<sup>^{\</sup>rm 2}$  Control input must be monotonic from 20% to 80% of input swing.

<sup>&</sup>lt;sup>3</sup> Time from deassertion until outputs are > 200 mV.

<sup>&</sup>lt;sup>4</sup> DIF\_IN input.



# **Electrical Characteristics – DIF HCSL/LP-HCSL Outputs**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on	1.5	2.2	3.0	0.6 - 4	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		7.3	18	20	%	1,2,4,7
Max Voltage	Vmax	Measurement on single ended signal using	719	772	842	1150	mV	7,8
Min Voltage	Vmin	absolute value. (Scope averaging off)		11	50	-300	IIIV	7,8
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	310	367	400	250 - 550	mV	1,5,7
Crossing Voltage (var)	Δ-Vcross	Scope averaging off		14	30	140	mV	1,6,7

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> Measured from differential waveform

<sup>&</sup>lt;sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

<sup>&</sup>lt;sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>&</sup>lt;sup>5</sup> Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>&</sup>lt;sup>6</sup> The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross\_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting ↑-Vcross to be smaller than Vcross absolute.

<sup>&</sup>lt;sup>7</sup> At default SMBus settings.

<sup>&</sup>lt;sup>8</sup> If driving a receiver with input terminations, the Vmax and Vmin values will be halved.



#### **Electrical Characteristics – Skew and Differential Jitter Parameters**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
CLK_IN, DIF[x:0]	t <sub>SPO_PLL</sub>	Input-to-Output Skew in PLL mode at 100MHz, nominal temperature and voltage	-100	54	100	ps	1,2,4,5,8
CLK_IN, DIF[x:0]	t <sub>PD_BYP</sub>	Input-to-Output Skew in Bypass mode at 100MHz, nominal temperature and voltage	1.9	2.6	3	ns	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>DSPO_PLL</sub>	Input-to-Output Skew Variation in PLL mode at 100MHz, across voltage and temperature	-50	0.0	50	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>DSPO_BYP</sub>	Input-to-Output Skew Variation in Bypass mode at 100MHz, across voltage and temperature, $T_{\text{AMB}} = T_{\text{COM}}$	-250	0.0	250	ps	1,2,3,5,8
DIF[x:0]	t <sub>SKEW_ALL</sub>	Output-to-Output Skew across all outputs, common to PLL and Bypass mode, at 100MHz		32	50	ps	1,2,3,8
PLL Jitter Peaking	<b>j</b> peak-hibw	LOBW#_BYPASS_HIBW = 1	0	1.4	2.5	dB	7,8
PLL Jitter Peaking	j <sub>peak-lobw</sub>	LOBW#_BYPASS_HIBW = 0	0	1.2	2	dB	7,8
PLL Bandwidth	pll <sub>HIBW</sub>	LOBW#_BYPASS_HIBW = 1	2	2.8	4	MHz	8,9
PLL Bandwidth	pll <sub>LOBW</sub>	LOBW#_BYPASS_HIBW = 0	0.7	1.1	1.4	MHz	8,9
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	50	55	%	1
Duty Cycle Distortion	t <sub>DCD</sub>	Measured differentially, Bypass Mode at 100MHz	-1	-0.5	0	%	1,10
littor Cycle to Cycle		PLL mode		17	50	ps	1,11
Jitter, Cycle to Cycle	t <sub>jcyc-cyc</sub>	Additive Jitter in Bypass Mode		0.1	5	ps	1,11

<sup>&</sup>lt;sup>1</sup> Measured into fixed 2 pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

<sup>&</sup>lt;sup>2</sup> Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

<sup>&</sup>lt;sup>3</sup> All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

<sup>&</sup>lt;sup>4</sup> This parameter is deterministic for a given device.

<sup>&</sup>lt;sup>5</sup> Measured with scope averaging on to find mean value.

<sup>&</sup>lt;sup>6</sup> t is the period of the input clock.

<sup>&</sup>lt;sup>7</sup> Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

<sup>&</sup>lt;sup>8.</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>9</sup> Measured at 3 db down or half power point.

<sup>&</sup>lt;sup>10</sup> Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

<sup>&</sup>lt;sup>11</sup> Measured from differential waveform.



# Electrical Characteristics – Filtered Phase Jitter Parameters - PCle Common Clocked (CC) Architectures

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	Notes
	t <sub>jphPCleG1-CC</sub>	PCIe Gen 1		18	30	86	ps (p-p)	1,2,3
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		0.4	0.8	3	ps (rms)	1,2
Phase Jitter, PLL Mode	t <sub>jphPCleG2-CC</sub>	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		1.1	1.6	3.1	ps (rms)	1,2
	t <sub>jphPCleG3-CC</sub>	PCIe Gen 3 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.28	0.40	1	ps (rms)	1,2
	t <sub>jphPCleG4-CC</sub>	PCIe Gen 4 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.28	0.40	0.5	ps (rms)	1,2
	t <sub>jphPCleG1-CC</sub>	PCIe Gen 1		0.1	0.1		ps (p-p)	1,2
	t <sub>jphPCleG2-CC</sub>	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		0.1	0.1		ps (rms)	1,2,4
Additive Phase Jitter, Bypass mode		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		0.105	0.13	n/a	ps (rms)	1,2,4
	$\begin{array}{c} \text{PCIe Gen 3} \\ \text{(PLL BW of 2-4MHz or 2-5MHz, CDR} = 10MHz) \end{array}$			0.1	0.1		ps (rms)	1,2,4
	t <sub>jphPCleG4-CC</sub>	PCIe Gen 4 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.1	0.1		ps (rms)	1,2,4

<sup>&</sup>lt;sup>1</sup> Applies to all outputs,, when driven by 9SQL4958 or equivalent

<sup>&</sup>lt;sup>2</sup> Based on PCle Base Specification Rev4.0 version 0.7 draft. See http://www.pcisig.com for latest specifications.

<sup>&</sup>lt;sup>3</sup> Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

<sup>&</sup>lt;sup>4</sup> For RMS values additive jitter is calculated by solving the following equation for b  $[a^2+b^2=c^2]$  where a is rms input jitter and c is rms total jitter.



# Electrical Characteristics – Filtered Phase Jitter Parameters - PCle Separate Reference Independent Spread (SRIS) Architectures

Over specified temperature and voltage ranges unless otherwise indicated. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	Notes
	t <sub>jphPCleG1-</sub> SRIS	PCIe Gen 1		n/a		n/a	ps (p-p)	1,2,3
Phase Jitter, PLL	t <sub>jphPCleG2</sub> - SRIS	PCIe Gen 2 (PLL BW of 16MHz , CDR = 5MHz)		0.8	1.1	2	ps (rms)	1,2
Mode	t <sub>jphPCleG3-</sub> SRIS	PCIe Gen 3 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.6	0.7	TBD	ps (rms)	1,2
	t <sub>jphPCleG4-</sub> SRIS	PCIe Gen 4 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)			n/a	ps (rms)	1,2	
	t <sub>jphPCleG1</sub> - SRIS	PCle Gen 1		n/a			ps (p-p)	1,2
AdditivePhase Jitter,	t <sub>jphPCleG2</sub> - SRIS	PCIe Gen 2 (PLL BW of 16MHz , CDR = 5MHz)		0.0	0.01	n/a	ps (rms)	1,2,4
Bypass mode	s mode $t_{jphPCleG3-}$ PCle Gen 3 SRIS (PLL BW of 2-4MHz or 2-5MHz, CDR = 10			0.0	0.01	II/a	ps (rms)	1,2,4
	$\begin{array}{c} t_{jphPCleG4-} \\ \text{SRIS} \end{array} \hspace{0.5cm} \begin{array}{c} \text{PCle Gen 4} \\ \text{(PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)} \end{array}$			n/a			ps (rms)	1,2,4

<sup>&</sup>lt;sup>1</sup> Applies to all outputs, when driven by 9SQL4958 or equivalent

## Electrical Characteristics - Filtered Phase Jitter Parameters - QPI/UPI

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	IND.LIMIT	UNITS	Notes
		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.15	0.3	0.5	ps (rms)	1,2
Phase Jitter, PLL Mode		QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.08	0.12	0.3	ps (rms)	1,2
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.07	0.1	0.2	ps (rms)	1,2
		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.009	0.12		ps (rms)	1,2,3
Additive Phase Jitter, Bypass mode	T:KODI LIDI	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.020	0.07	n/a	ps (rms)	1,2,3
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.016	0.06		ps (rms)	1,2,3

<sup>&</sup>lt;sup>1</sup> Applies to all outputs, when driven by 9SQL4958 or equivalent

<sup>&</sup>lt;sup>2</sup> Preliminary based on PCIe Base Specification Rev3.1a. PCIe Gen4 is expected to remove the SRIS specifications. These filters are different than Common Clock filters. See http://www.pcisig.com for latest specifications.

<sup>&</sup>lt;sup>3</sup> Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

<sup>&</sup>lt;sup>4</sup> For RMS values, additive jitter is calculated by solving the following equation for b  $[a^2+b^2=c^2]$  where a is rms input jitter and c is rms total

<sup>&</sup>lt;sup>2</sup> Calculated from Intel-supplied Clock Jitter Tool v 1.6.6

<sup>&</sup>lt;sup>3</sup> For RMS values additive jitter is calculated by solving the following equation for b  $[a^2+b^2=c^2]$  where a is rms input jitter and c is rms total jitter.



#### Electrical Characteristics - Unfiltered Phase Jitter Parameters - 12kHz to 20MHz

Over specified temperature and voltage ranges unless otherwise indicated. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	IND.LIMIT	UNITS	Notes
Phase Jitter, PLL Mode	t <sub>jph12k-20MHi</sub>	PLL High BW, SSC OFF, 100MHz	161	178	198	n/a	fs (rms)	1,2
Phase Jitter, PLL Mode	t <sub>jph12k-20MLo</sub>	PLL Low BW, SSC OFF, 100MHz	175	193	207	n/a	fs (rms)	1,2
Additive Phase Jitter, Bypass mode	t <sub>jph12k-20MByp</sub>	Bypass Mode, SSC OFF, 100MHz	104	104	110	n/a	fs (rms)	1,2,3

<sup>&</sup>lt;sup>1</sup> Applies to all outputs.

**Power Management Table** 

Inputs		Control B	its/Pins		Outputs		
CKPWRGD_PD#	DIF_IN/ DIF_IN#	SMBus EN bit	OE# Pin	DIF(5:12)	Other DIF	DFB_OUT	PLL State
0	Х	Х	Х	Hi-Z <sup>1</sup>	Hi-Z <sup>1</sup>	Hi-Z <sup>1</sup>	OFF
		0	Х	Hi-Z <sup>1</sup>	Hi-Z <sup>1</sup>	Running	ON
1	Running	1	0	Running	Running	Running	ON
		1	1	Hi-Z <sup>1</sup>	Running	Running	NO

NOTE: 1. Due to external pull down resistors, HI-Z results in Low/Low on the True/Complement outputs

## Clock Periods – Differential Outputs with Spread Spectrum Disabled

				Меа	surement Wi	indow				
	Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3
DIF	133.33	7.44925		7.49925	7.50000	7.50075		7.55075	ns	1,2,4

# Clock Periods – Differential Outputs with Spread Spectrum Enabled

				Mea	surement Wi	ndow				
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC ON	Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3
DIF	133.00	7.44930	7.49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	1,2,4

#### Notes:

<sup>&</sup>lt;sup>2</sup> 12kHz to 20MHz brick wall filter.

<sup>&</sup>lt;sup>3</sup> For RMS values additive jitter is calculated by solving the following equation for b  $[a^2+b^2=c^2]$  where a is rms input jitter and c is rms total jitter.

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ accuracy requirements (+/-100ppm). The device itself does not contribute to ppm error.

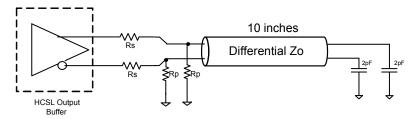
<sup>&</sup>lt;sup>3</sup> Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

<sup>&</sup>lt;sup>4</sup> Driven by CPU output of main clock, 133 MHz PLL Mode or Bypass mode



## **Test Loads**

9ZX21901D Characterization Test Loads



#### **Differential Output Termination Table**

DIF Zo (Ω)	Iref (Ω)	Rs $(\Omega)$	Rp (Ω)
100	475	33	50
85	412	27	42.2 or 43.2

## **Alternate Terminations**

The 9ZX21901D can easily drive LVPECL, LVDS, CML, and SSTL logic. See <u>"AN-891 Driving LVPECL, LVDS, CML, and SSTL Logic with IDT's "Universal" Low-Power HCSL Outputs"</u> for details.



#### **General SMBus Serial Interface Information**

(see also 9ZX21901 SMBus Addressing on page 2)

#### **How to Write**

- Controller (host) sends a start bit
- Controller (host) sends the write address XX<sub>(H)</sub>
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index BI	ock '	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	g Byte N		
			ACK
0		×	
0		X Byte	0
0		Ö	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: XX<sub>(H)</sub> is defined by SMBus Address select pins.

#### How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address XX<sub>(H)</sub>
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address YY(H)
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block Read Operation							
Cor	ntroller (Host)		IDT (Slave/Receiver)					
Т	starT bit							
SI	ave Address							
WR	WRite							
			ACK					
Begi	nning Byte = N							
			ACK					
RT	Repeat starT							
SI	ave Address							
RD	ReaD							
			ACK					
			Data Byte Count=X					
	ACK							
			Beginning Byte N					
	ACK							
		ē	0					
	0	X Byte	0					
	0	×	0					
	0							
			Byte N + X - 1					
N	Not acknowledge							
Р	stoP bit							



SMBusTable: PLL Mode, and Frequency Select Register

Byte	0 Pin	Name	Control Function	Type	0	1	Default
Bit 7	5	PLL Mode 1	PLL Operating Mode Rd back 1	R	See PLL Operating Mode		Latch
Bit 6	5	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readback Table		Latch
Bit 5	72/71	DIF_18_En	Output Enable	RW	Hi-Z	Enable	1
Bit 4	70/69	DIF_17_En	Output Enable	RW	Hi-Z	Enable	1
Bit 3	67/66	DIF_16_En	Output Enable	RW	Hi-Z	Enable	1
Bit 2		Reserved					0
Bit 1		Reserved					0
Bit 0	4	100M 133M#	Frequency Select Readback	R	133MHz	100MHz	Latch

SMBusTable: Output Control Register

Byte	1 Pin	Name	Control Function	Туре	0	1	Default
Bit 7	39/38	DIF_7_En	Output Enable	RW		OE# pin	
Bit 6	35/36	DIF_6_En	Output Enable	RW		controlled	1
Bit 5	32/33	DIF_5_En	Output Enable	RW			1
Bit 4	29/30	DIF_4_En	Output Enable	RW	Hi-Z		1
Bit 3	27/28	DIF_3_En	Output Enable	RW	⊓I-Z		1
Bit 2	24/25	DIF_2_En	Output Enable	RW		Enable	1
Bit 1	22/23	DIF_1_En	Output Enable	RW			1
Bit 0	19/20	DIF_0_En	Output Enable	RW			1

SMBusTable: Output Control Register

Byte	2 Pin	Name	Control Function	Type	0	1	Default
Bit 7	65/64	DIF_15_En	Output Enable	RW			1
Bit 6	62/61	DIF_14_En	Output Enable	RW		Enable	1
Bit 5	60/59	DIF_13_En	Output Enable	RW			1
Bit 4	56/55	DIF_12_En	Output Enable	RW	Hi-Z		1
Bit 3	53/52	DIF_11_En	Output Enable	RW	1 11-2	OE# pin	1
Bit 2	50/49	DIF_10_En	Output Enable	RW		controlled	1
Bit 1	47/46	DIF_9_En	Output Enable	RW		Controlled	1
Bit 0	42/41	DIF_8_En	Output Enable	RW			1

SMBusTable: Output Enable Pin Status Readback Register

Byte	9 3	Pin	Name	Control Function	Type	0	1	Default
Bit 7	5	57	OE_RB12	Real Time readback of OE#12	R			Real time
Bit 6	5	54	OE_RB11	Real Time readback of OE#11	R	OF# pip   our	OE# Pin High	Real time
Bit 5	5	51	OE_RB10	Real Time readback of OE#10	R			Real time
Bit 4	4	18	OE_RB9	Real Time readback of OE#9	R			Real time
Bit 3	4	13	OE_RB8	Real Time readback of OE#8	R	OE# pill Low		Real time
Bit 2	4	10	OE_RB7	Real Time readback of OE#7	R			Real time
Bit 1	3	37	OE_RB6	Real Time readback of OE#6	R			Real time
Bit 0	3	34	OE_RB5	Real Time readback of OE#5	R			Real time

SMBusTable: PLL SW Override Control Register

Byte	4 P	Pin	Name	Control Function	Type	0	1	Default	
Bit 7		Reserved					0		
Bit 6				Reserved					
Bit 5			Reserved						
Bit 4			Reserved					0	
Bit 3			PLL_SW_EN	Enable S/W control of PLL BW	RW	HW Latch	SMBus Control	0	
Bit 2			PLL Mode 1 PLL Operating Mode 1 RW See PLL Operating Mode			erating Mode	0		
Bit 1			PLL Mode 0	PLL Operating Mode 1	RW	Readba	0		
Bit 0				Reserved				0	

**Note:** Setting bit 3 to '1' allows the user to override the Latch value from pin 4 via use of bits 2 and 1. Use the values from the PLL Operating Mode Readback Table. Note that Byte 0, Bits 7:6 will keep the value originally latched on pin 4. A warm reset of the system will have to be completed if the user changes these bits.



SMBusTable: Vendor & Revision ID Register

Byte	95 Pin	Name	Control Function	Type	0	1	Default
Bit 7	-	RID3		R			0
Bit 6	•	RID2	REVISION ID R D rev = 0011		0011	0	
Bit 5	1	RID1	HEVISION ID	R D rev = 0011	1		
Bit 4	-	RID0				1	
Bit 3	ı	VID3			-	-	0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID1	VENDOR ID	R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBusTable: DEVICE ID

Byte 6	Pin	Name	Control Function	Туре	0	1	Default
Bit 7	-	Device ID 7 (MSB)		R			1
Bit 6	-		Device ID 6	R			1
Bit 5	-		Device ID 5	R			0
Bit 4	-		Device ID 4	R	Device ID is 219 decimal or		1
Bit 3	-		Device ID 3	R	DB	1	
Bit 2	-		Device ID 2	R			0
Bit 1	-	<del>-</del>	Device ID 1	R			1
Bit 0	-		Device ID 0	R			1

SMBusTable: Byte Count Register

Byte	e 7	Pin	Name	Control Function	Type	0	1	Default
Bit 7			Reserved					0
Bit 6				Reserved				
Bit 5			Reserved					
Bit 4	-		BC4		RW			0
Bit 3			BC3	Writing to this register configures how	RW	Default value	is 8 hex, so 9	1
Bit 2			BC2	many bytes will be read back.	RW	bytes (0 to 8) v	vill be read back	0
Bit 1			BC1	many bytes will be read back.	RW	by de	efault.	0
Bit 0	_		BC0		RW	]		0

SMBusTable: Reserved Register

		or roa riogrator					
Byte 8	Pin	Name	Control Function	Type	0	1	Default
Bit 7			Reserved				0
Bit 6			Reserved				0
Bit 5			Reserved				
Bit 4		Reserved				0	
Bit 3			Reserved				0
Bit 2		Reserved				0	
Bit 1		Reserved				0	
Bit 0		Reserved				0	



#### **Package Outline Drawings**

The package outline drawings are appended at the end of this document and are accessible from the link below. The package information is the most current data available.

www.idt.com/document/psc/nlnlg72-package-outline-100-x-100-mm-body-epad-59-mm-sq-050-mm-pitch-vfqfpn-sawn

#### **Thermal Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
	θЈА	Still air		28.2		°C/W
Thermal Resistance Junction to Ambient	θЈА	1 m/s air flow		21.6		°C/W
	θЈА	3 m/s air flow		17.9		°C/W
Thermal Resistance Junction to Case	θЈС			14.4		°C/W
Thermal Resistance Junction to Board	θЈВ			0.61		°C/W

# **Marking Diagram**



#### Notes:

- 1. "LOT" is the lot sequence number.
- 2. "COO" denotes country of origin.
- 3. "YYWW" is the last two digits of the year and week that the part was assembled.
- 4. "LF" denotes RoHS compliant package.

## **Ordering Information**

Part / Order Number	Shipping Package	Package	Temperature		
9ZX21901DKLF	Trays	72-pin VFQFPN	0 to +70°C		
9ZX21901DKLFT	Tape and Reel	72-pin VFQFPN	0 to +70°C		

<sup>&</sup>quot;LF" designates PB-free configuration, RoHS compliant.

<sup>&</sup>quot;D" designates die revision and does not correlate to data sheet revision.



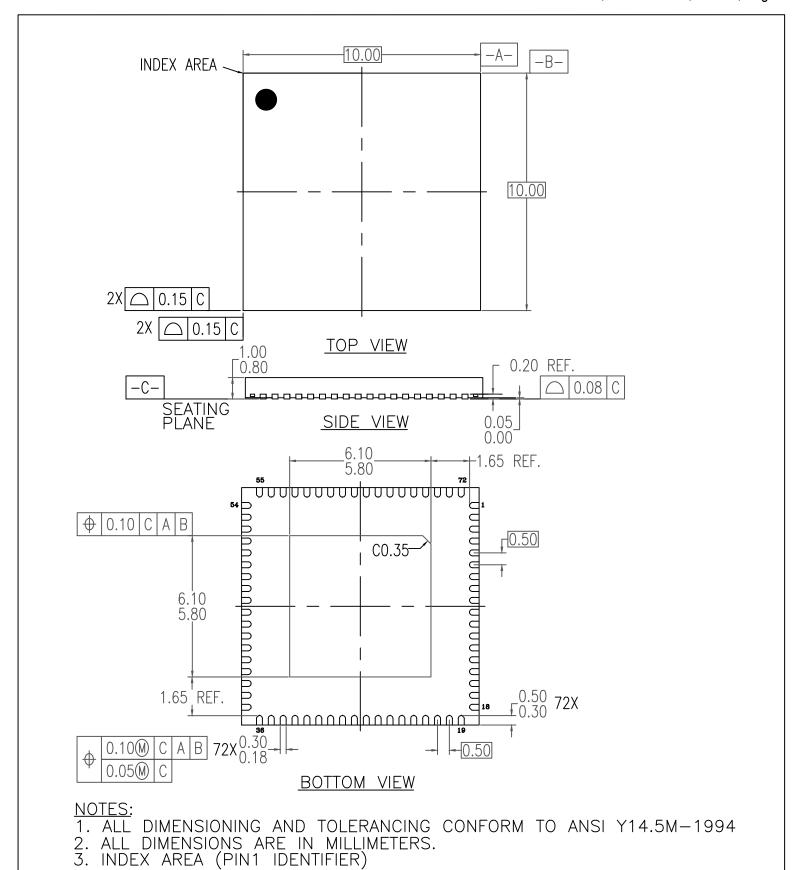
# **Revision History**

Issue Date	Description		
9/16/2016	1. Updated electrical tables		
	2. Move to Final		
10/5/2016	Changed IDD maximum value from 450 to 490mA		
2/15/2017	1. Features change: "Hardware or software control of PLL operating mode; change mode with software mode does not need power cycle."  2. Change Max of Powerdown Current IDDPD to 5mA.  3. Input frequency of PLL mode:  (1). Change Min of 100MHz to 98.5HMz and Max of 100MHz to 102MHz.  (2). Change Max of 133.33MHz to 130.5MHz and Max of 133.33MHz to 135MHz.  4. DIF HCSL/LP-HCSL Outputs:  (1). Change Min of Max Voltage to 719mV and Max of Max Voltage to 842mV.  (2). Change Min of (Crossing Voltage (abs)) to 310mV and Max of (Crossing Voltage (abs)) to 400mV.  5. Change Typ of Cycle to cycle jitter of PLL mode to 17ps.  6. Filtered Phase Jitter Parameters - PCle Common Clocked  (CC) Architectures"  (1). Change Typ of additive phase jitter of bypass mode of PCle Gen1 to 0.1.  (2). Change Typ and max of additive phase jitter of bypass mode of PCle Gen2 Lo Band to 0.1.  (3). Change Typ and max of additive phase jitter of bypass mode of PCle Gen3 to 0.1.  (4). Change Typ and max of additive phase jitter of bypass mode of PCle Gen4 to 0.1.  7. Unfiltered Phase Jitter Parameters - 12kHz to 20MHz  (1). Change Min, TYP and Max of PLLmode High BW to 161, 178, 198ps.  (2). Change Min, TYP and Max of Bpmode to 104, 104, 110ps.		
	Removed "5V tolerant" reference in pins 12 and 13 descriptions.		
4/17/2018	Updated absolute maximum supply voltage rating and VIHSMB to 3.9V.		



## 72-VFQFPN, Package Outline Drawing

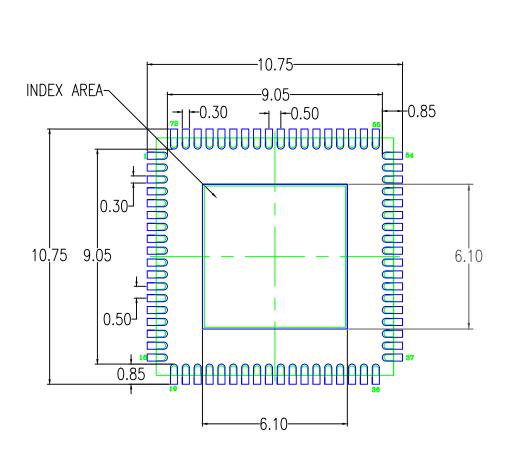
10.0 x 10.0 x 0.90 mm Body, Epad 5.95 x 5.95 mm 0.50mm Pitch NLG72P1, PSC-4208-01, Rev 03, Page 1





## 72-VFQFPN, Package Outline Drawing

10.0 x 10.0 x 0.90 mm Body, Epad 5.95 x 5.95 mm 0.50mm Pitch NLG72P1, PSC-4208-01, Rev 03, Page 2



#### RECOMMENDED LAND PATTERN DIMENSION

#### NOTES:

- DIMENSIONS ARE IN MM. ANGLES IN DEGREES.
- 2. TOP DOWN VIEW. AS VIEWED ON PCB.
  3. COMPONENT OUTLINE SHOWS FOR REFERENCE IN G
  4. LAND PATTERN IN BLUE. NSMD PATTERN ASSUMED. SHOWS FOR REFERENCE IN GREEN.
- 5. LAND PATTERN RECOMMENDATION PER IPC-7351B GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN.

Package Revision History			
Date Created	Rev No.	Description	
Sept 3, 2019	Rev 03	Update P1 Dimension from 5. 8 to 5.95 mm SQ	
May 8, 2017	Rev 02	Change Package Code QFN to VFQFPN	

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PI6C4931502-04LIE NB7L1008MNG NB7L14MN1G PI49FCT20807QE PI6C4931502-04LIEX ZL80002QAB1 PI6C4931504-04LIEX
PI6C10806BLEX ZL40226LDG1 ZL40219LDG1 8T73S208B-01NLGI SY75578LMG PI49FCT32805QEX PL133-27GC-R
CDCV304PWG4 MC10LVEP11DG MC10EP11DTG MC100LVEP11DG MC100E111FNG MC100EP11DTG NB6N11SMNG
NB7L14MMNG NB6L11MMNG NB6L14MMNR2G NB6L611MNG PL123-02NGI-R NB3N111KMNR4G ADCLK944BCPZ-R7
ZL40217LDG1 NB7LQ572MNG HMC940LC4BTR ADCLK946BCPZ-REEL7 ADCLK946BCPZ ADCLK846BCPZ-REEL7
ADCLK905BCPZ-R2